PCN Number:		20151016001C			PCN Date:	08/2/2016			
Title:Qualification of AMKOR Package Devices				P1 as	s Additional Asse	mbly and T	est	Site for Sele	ct SOIC
Cus	tomer	Contact:	PCN Manage	<u>er</u>	Dept:	Quality Se	rvic	es	
Cha	nge T								
Assembly Site				Design			Wafer Bum	p Site	
Assembly Process			Data Sheet			Wafer Bum	p Material		
Assembly Materials			Part number ch	nange		Wafer Bum	p Process		
Mechanical Specification		ation	\boxtimes	Test Site			Wafer Fab	Site	
\boxtimes	Packing/Shipping/Labeling				Test Process			Wafer Fab	Materials
	Wafer Fab Process					Process			
	PCN Details								

Description of Change:

Revision C is to update the description of change to provide correction on the pin 1 marking change. Only 14pin SOIC devices are affected for the embossed pin 1 ID. We apologize for any inconvenience this may have caused.

Texas Instruments Incorporated is announcing the qualification of AMKOR P1 as Additional Assembly and Test Site for select devices listed in the "Product Affected" Section. Current assembly sites and Material differences are as follows.

Assembly Site	Assembly Site Origin	Assembly Country Code	Assembly Site City
TI Mexico	MEX	MX	Aguascalientes
TI Malaysia	MLA	MY	Kuala Lumpur
ASESH	ASH	CN	Shanghai
Amkor P1	AKR	PH	Cupang, Muntinlupa City

Material Differences:

Group 1 Devices:

	TI Mexico	TI Malaysia	ASESH	AMKOR P1
Mount Compound	4147858	4042500	EY1000063	101375281
Mold Compound	4211880	4211880	EN20000509	101380756
Lead Finish	NiPdAu	NiPdAu	Matte Sn	Matte Sn

Group 2 Devices:

	ASESH	AMKOR P1
Mount Compound	EY1000063	101375281
Wire Type	Au	Cu
Mold Compound	EN20000509	101380756
Lead Finish	Matte Sn	Matte Sn

Upon expiration of this PCN, TI will combine lead free solutions in a single <u>standard part number</u>, for example; <u>LM224ADR</u> – can ship with both Matte Sn and NiPdAu. When available customers may specify NiPdAu finish by ordering the part with the G4 suffix, e.g. **LM224ADRG4**."

Test coverage, insertions, conditions will remain consistent with current testing and verified with test MQ.

<mark>'in 1</mark>	L Marking Chang	e for 14 p	<mark>oin Devices only:</mark>			
	Sample Ma	rking:				
	Current			Proposed		
		1 39P2EDA <u>63</u> LN324A			JLM339	
		Stripe pin	1 ID	Embossed	pin 1 ID	
leas	son for Change:					
	inuity of supply.					
		n Form	it. Function Qua	lity or Reliability	(positive / negative):	
lone			it, i unction, qua	ity of Reliability	(positive / negative):	
	cipated impact o	n Materia	Declaration			
	No Impact to the			ons or Product Con	tent reports are driven from	
	Material Declarat		production data ar	nd will be available duction release the	or Product Content reports are driven from ill be available following the production ion release the revised reports can be <u>CO website</u> .	
	sembly Site	1	<u></u>			
	Mexico		y Site Origin (22L) y Site Origin (22L)	ASO: MEX ASO: MLA	ECAT: G4 ECAT: G4	
	<u>Malaysia</u> ESH		y Site Origin (22L)	ASO: MLA	ECAT: G3	
	Lon P1		y Site Origin (22L)	ASO: ASN	ECAT: G3	
*	TEXAS	B	(not actual product ECAT: G4 = NiPdA ECAT: G3 = Matte	u	SR	
MAI 2DO MSI MSI 0P1 ITE	DE IN: Malaysia C: 201: L'2 /260C/1 YEAR L 1 /235C/UNLIM (T:	3/29/04 39		(Q) 2000 (I (31T)LOT: 3959 (4W) TKY(1T) 75 (P) (2P) REV: (V) (20L) CSO: SHE (21)	D) 0336	
SSE	MBLY SITE CODE	S: TI-Mex	ico = M , TI-Malays	sia = K , ASESH =	A , AP1 = 4	

Product Affected: Group 1					
LM224ADR	LM324ADR	LM358ADR	LM2904DRG3		
LM224DR	LM324DR	LM2901DR	LM358DR		
LM224DRG3	LM324DRG3	LM2901DRG3	LM358DRG3		
LM239DR	LM324DR-M	LM2902DR	LM393DR		
LM239DRG3	LM339DR	LM2903DR	LM393DR-V1		
LM258DR	LM339DRG3	LM2904DR	NE555DRG3		
Product Affected: Group 2					
LM258DRG3	LM2903DRG3	LM393DRG3	NE555DR		

Qualification Report

Amkor SOIC - 8D Offload

Product Attributes

Attributes	Qual Device: LM358DR	Qual Device: LM393DR			
Assembly Site	AMKOR AP1	AMKOR AP1			
Package Family	SOIC	SOIC			
Flammability Rating	UL 94 V-0	UL 94 V-0			
Wafer Fab Supplier	SFAB	SFAB			
Wafer Process	JI1	JI1			

- QBS: Qual By Similarity

- Qual Devices qualified at LEVEL1-260CG: LM358DR, LM393DR

Qualification Results

Data Displayed as: Number of lots / Total sample size / Total failed

Туре	Test Name / Condition	Duration	Qual Device: LM358DR	Qual Device: LM393DR
AC	Autoclave 121C	96 Hours	3/231/0	3/231/0
ED	Electrical Characterization	Per Datasheet Parameters	Pass	Pass
FLAM	Flammability (IEC 695-2-2)		3/15/0	3/15/0
FLAM	Flammability (UL 94V-0)		3/15/0	3/15/0
FLAM	Flammability (UL-1694)		3/15/0	3/15/0
HAST	Biased HAST, 130C/85%RH	96 Hours	3/231/0	3/231/0
HTOL	Life Test, 150C	300 Hours	3/231/0	-
HTSL	High Temp. Storage Bake, 170C	420 Hours	3/229/0	3/231/0
LI	Lead Fatigue	Leads	3/66/0	3/66/0
LI	Lead Pull to Destruction	Leads	3/66/0	3/66/0
PD	Physical Dimensions		3/60/0	3/60/0
SD	Solderability	PB Free	3/66/0	3/66/0
TC	Temperature Cycle, -65/150C	500 cycles	3/230/0	3/231/0
WBP	Bond Pull	Wires	3/228/0	3/228/0
WBS	Ball Bond Shear	Wires	3/228/0	3/228/0

- Preconditioning was performed for Autoclave, Unbiased HAST, THB/Biased HAST, Temperature Cycle, Thermal Shock, and HTSL, as applicable

- The following are equivalent HTOL options based on an activation energy of 0.7eV : 125C/1k Hours, 140C/480 Hours,

150C/300 Hours, and 155C/240 Hours

- The following are equivalent HTSL options based on an activation energy of 0.7eV : 150C/1k Hours, and 170C/420 Hours

- The following are equivalent Temp Cycle options per JESD47 : -55C/125C/700 Cycles and -65C/150C/500 Cycles

Quality and Environmental data is available at TI's external Web site: http://www.ti.com/

Green/Pb-free Status:

Qualified Pb-Free(SMT) and Green

Qualification Report

Amkor SOIC - 14D Offload

Product Attributes

Attributes	Qual Device: LM324ADR
Assembly Site	AMKOR P1
Package Family	SOIC
Flammability Rating	UL 94 V-0
Wafer Fab Supplier	SFAB
Wafer Process	JI1

- QBS: Qual By Similarity

- Qual Device LM324ADR is qualified at LEVEL1-260CG

Qualification Results

Data Displayed as: Number of lots / Total sample size / Total failed

Туре	Test Name / Condition	Duration	Qual Device: LM324ADR
AC	Autoclave 121C	96 Hours	3/231/0
ED	Electrical Characterization	Per Datasheet Parameters	Pass
FLAM	Flammability (IEC 695-2-2)		3/15/0
FLAM	Flammability (UL 94V-0)		3/15/0
FLAM	Flammability (UL-1694)		3/15/0
HAST	Biased HAST, 130C/85%RH	96 Hours	3/231/0
HTOL	Life Test, 150C	300 hours	3/231/0
HTSL	High Temp. Storage Bake, 170C	420 Hours	3/229/0
LI	Lead Fatigue	Leads	3/66/0
LI	Lead Pull to Destruction	Leads	3/66/0
PD	Physical Dimensions		3/60/0
SD	Solderability	PB-Free	3/66/0
TC	Temperature Cycle -65/150C	500 Cycles	3/231/0
WBP	Bond Pull	Wires	3/228/0
WBS	Ball Bond Shear	Wires	3/228/0

- Preconditioning was performed for Autoclave, Unbiased HAST, THB/Biased HAST, Temperature Cycle, Thermal Shock, and HTSL, as applicable

- The following are equivalent HTOL options based on an activation energy of 0.7eV : 125C/1k Hours, 140C/480 Hours, 150C/300 Hours, and 155C/240 Hours

- The following are equivalent HTSL options based on an activation energy of 0.7eV : 150C/1k Hours, and 170C/420 Hours

- The following are equivalent Temp Cycle options per JESD47 : -55C/125C/700 Cycles and -65C/150C/500 Cycles Quality and Environmental data is available at TI's external Web site: http://www.ti.com/

Green/Pb-free Status:

Qualified Pb-Free(SMT) and Green

For questions regarding this notice, e-mails can be sent to the regional contacts shown below or your local Field Sales Representative.

Location	E-Mail
USA	PCNAmericasContact@list.ti.com
Europe	PCNEuropeContact@list.ti.com
Asia Pacific	PCNAsiaContact@list.ti.com
Japan	PCNJapanContact@list.ti.com